

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): FUKUDA et al.	Atty. Dkt.: 01-493
Serial No.: Unknown	Group Art Unit:
Filed: Concurrently herewith	Examiner:
Title: SEMICONDUCTOR EQUIPMENT	

Commissioner for Patents
Arlington, VA 22202

Date: October 21, 2003

INFORMATION DISCLOSURE STATEMENT

Sir:

Pursuant to 37 C.F.R. §1.56, the reference(s) listed on the attached Form PTO-1449 is/are submitted for consideration by the Examiner without any admission that it/they constitute(s) statutory prior art, or without any admission that it/they contain(s) subject matter that anticipates the invention or renders the invention obvious to a person of ordinary skill in the art.

The Examiner is requested to initial the attached PTO Form-1449 and to return a copy of same to the undersigned attorney as proof that the listed reference(s) has/have been considered and made of record.

Respectfully submitted,



David G. Posz
Reg. No. 37,701

Posz & Bethards, PLC
11250 Roger Bacon Drive, Suite 10
Reston, VA 20190
(703)707-9110 (phone)
Customer No. 23400

FORM PTO-1449	ATTY. DKT NO.	01-493	SER. NO.
	APPLICANT	FUKUDA et al.	
	FILING DATE	October 21, 2003	GROUP

REFERENCE DESIGNATION

U.S. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS
	4,636,825	Jan. 13, 1987	Baynes		
	4,948,754	Aug. 14, 1990	Kondo et al.		
	5,192,989	Mar. 9, 1993	Matsushita et al.		
	5,412,239	May 2, 1995	Williams		
	5,672,894	Sep. 30, 1997	Maeda et al.		

FOREIGN PATENT DOCUMENTS

								TRANSLATION	
		DOCUMENT NUMBER	DATE	COUNTRY	NAME	CLASS	SUB CLASS	YES	NO
		JP-A-H07-263665 (Discussed in page 1 of the spec.)	10/13/95	JAPAN				X (Abstract)	
		JP-A-H03-239369	10/24/91	JAPAN				X (Abstract)	

* Full English text of the JP Document will be available in machine-translated form from JP (Japanese Patent Office) English language web site at <http://www1.ipdl.jpo.go.jp/PA1/cgi-bin/PA1INDEX>.

OTHER REFERENCES (including Author, Title, Date, Pertinent Pages, etc.)

	Hazel Schofield et al., "Assembly of FlipFET™ Devices", <u>International Rectifier</u> , AN-1011, 5/22/2000, pp.1-6
	"International Rectifier", IRF6150, PD-93943, pp. 1-3
	Hazel Schofield et al., "FlipFET™ MOSFET Design for High Volume SMT Assembly", <u>International Rectifier</u> , pp.1-6
EXAMINER	DATE CONSIDERED